1. General description

NPN/NPN matched double transistors in a small SOT457 (SC-74) Surface-Mounted Device (SMD) plastic package.

PNP/PNP complement: BCM53DS

2. Features and benefits

- High collector current capability I_C and I_{CM}
- Reduces component count
- · Reduces pick and place costs
- Current gain matching 5%
- · Application-optimized pinout
- AEC-Q101 qualified

3. Applications

- · Current mirror
- Differential amplifier
- · Linear voltage regulators
- MOSFET drivers
- High-side switches
- · Power management
- Amplifiers

4. Quick reference data

Table 1. Quick reference data

| Symbol | Parameter | Conditions | | Min | Тур | Max | Unit | |
|------------------------------------|---------------------------|---|-----|------|-----|------|------|--|
| Per transistor | | | | | | | | |
| V _{CEO} | collector-emitter voltage | open base | | - | - | 80 | V | |
| I _C | collector current | | | - | - | 1 | Α | |
| I _{CM} | peak collector current | single pulse; t _p ≤ 1 ms | | - | - | 2 | Α | |
| h _{FE} | DC current gain | V_{CE} = 2 V; I_{C} = 150 mA; T_{amb} = 25 °C | [1] | 63 | - | 250 | | |
| Per device | | | | | | | | |
| h _{FE1} /h _{FE2} | DC current gain matching | $V_{CE} = 5 \text{ V}; I_{C} = 2 \text{ mA}; T_{amb} = 25 \text{ °C}$ | | 0.95 | 1 | 1.05 | | |



80 V, 1 A NPN/NPN matched double transistors

| Symbol | Parameter | Conditions | | Min | Тур | Max | Unit |
|------------------------------------|-------------------------------|------------|-----|-----|-----|-----|------|
| V _{BE1} -V _{BE2} | base-emitter voltage matching | | [2] | - | - | 2 | mV |

- [1] Pulse test: $t_0 \le 300 \,\mu\text{s}$; $\delta \le 0.02$
- [2] The smaller of the two values is subtracted from the larger value.

5. Pinning information

Table 2. Pinning information

| Pin | Symbol | Description | Simplified outline | Graphic symbol | |
|-----|--------|---------------|--------------------|--------------------------------|--|
| 1 | B1 | base TR1 | <u> </u> | C1 E1 E2 | |
| 2 | B2 | base TR2 | | TR1 TR2 | |
| 3 | C2 | collector TR2 | <u>0</u> | | |
| 4 | E2 | emitter TR2 | TSOP6 (SOT457) | TSOP6 (SOT457) B1 B2 C2 | |
| 5 | E1 | emitter TR1 | | aaa-024629 | |
| 6 | C1 | collector TR1 | | | |

6. Ordering information

Table 3. Ordering information

| Type number | Package | Package | | | | | |
|-------------|---------|--|---------|--|--|--|--|
| | Name | Description | Version | | | | |
| BCM56DS | TSOP6 | plastic, surface-mounted package (SC-74) | SOT457 | | | | |

7. Marking

Table 4. Marking codes

| Type number | Marking code |
|-------------|--------------|
| BCM56DS | 3D |

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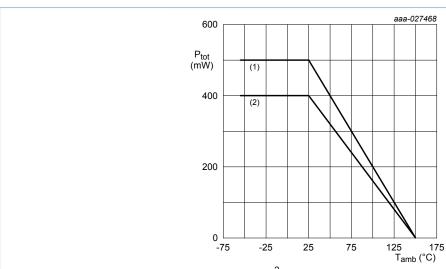
8. Limiting values

Table 5. Limiting values

In accordance with the Absolute Maximum Rating System (IEC60134).

| Symbol | Parameter | Conditions | | Min | Max | Unit |
|-------------------|---------------------------|-------------------------------------|-----|-----|-----|------|
| Per transisto | or | | , | | | |
| V _{CBO} | collector-base voltage | open emitter | | - | 100 | V |
| V _{CEO} | collector-emitter voltage | open base | | - | 80 | V |
| V _{EBO} | emitter-base voltage | open collector | | - | 5 | V |
| I _C | collector current | | | - | 1 | Α |
| I _{CM} | peak collector current | single pulse; t _p ≤ 1 ms | | - | 2 | Α |
| I _{Blim} | limiting base current | | | - | 0.2 | Α |
| I _{BM} | peak base current | single pulse; t _p ≤ 1 ms | | - | 0.3 | Α |
| P _{tot} | total power dissipation | T _{amb} ≤ 25 °C | [1] | - | 270 | mW |
| | | | [2] | - | 320 | mW |
| Per device | | | | | | , |
| P _{tot} | total power dissipation | T _{amb} ≤ 25 °C | [1] | - | 400 | mW |
| | | | [2] | - | 500 | mW |
| Tj | junction temperature | | | - | 150 | °C |
| T _{amb} | ambient temperature | | | -55 | 150 | °C |
| T _{stg} | storage temperature | | | -65 | 150 | °C |

- Device mounted on an FR4 Printed-Circuit Board (PCB), single-sided copper, tin-plated and standard footprint. Device mounted on an FR4 Printed-Circuit Board (PCB), single-sided copper, tin-plated; mounting pad for collector 1 cm².



- (1) = FR4 PCB, single sided copper, 1 cm^2
- (2) = FR4 PCB, single sided copper, standard footprint

Per device: Power derating curves Fig. 1.

80 V, 1 A NPN/NPN matched double transistors

9. Thermal characteristics

Table 6. Thermal characteristics

| Symbol | Parameter | Conditions | | Min | Тур | Max | Unit |
|-----------------------|--|-------------|-----|-----|-----|-----|------|
| Per transist | tor | | | | , | | |
| uiy-a) | thermal resistance | in free air | [1] | - | - | 463 | K/W |
| | from junction to ambient | | [2] | - | - | 391 | K/W |
| R _{th(j-sp)} | thermal resistance from junction to solder point | | | - | - | 150 | K/W |
| Per device | | | | | | | |
| R _{th(j-a)} | thermal resistance | in free air | [1] | - | - | 313 | K/W |
| | from junction to ambient | | [2] | - | - | 250 | K/W |

- [1] Device mounted on an FR4 PCB, single-sided copper, tin-plated and standard footprint.
- [2] Device mounted on an FR4 PCB, single-sided copper, tin-plated; mounting pad for collector 1 cm².

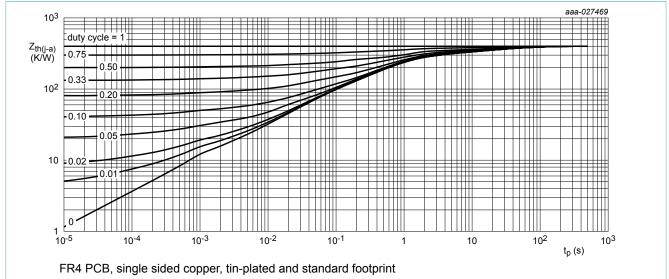
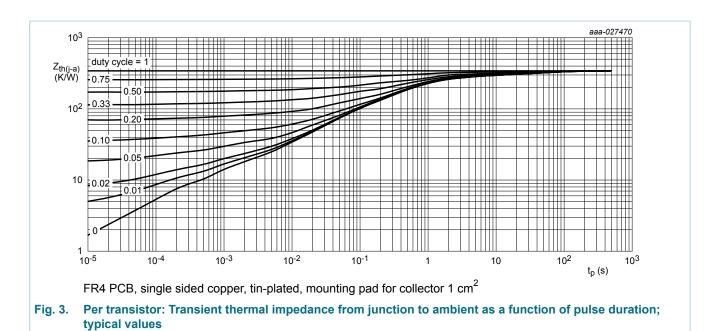


Fig. 2. Per transistor: Transient thermal impedance from junction to ambient as a function of pulse duration; typical values

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10. Characteristics

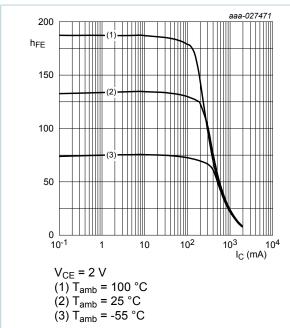
Table 7. Characteristics

| Symbol | Parameter | Conditions | | Min | Тур | Max | Unit |
|------------------------------------|--------------------------------------|--|-----|------|-----|------|------|
| Per transisto | or | | | , | | | |
| $V_{(BR)CBO}$ | collector-base breakdown voltage | I _C = 100 μA; I _E = 0 A | | 100 | - | - | V |
| $V_{(BR)CEO}$ | collector-emitter breakdown voltage | I _C = 2 mA; I _B = 0 A | | 80 | - | - | V |
| $V_{(BR)EBO}$ | emitter-base breakdown voltage | I _C = 0 A; I _E = 100 μA | | 5 | - | - | V |
| I _{CBO} | collector-base cut-off | V _{CB} = 30 V; I _E = 0 A; T _{amb} = 25 °C | | - | - | 100 | nA |
| current | | V _{CB} = 30 V; I _E = 0 A; T _j = 150 °C | | - | - | 10 | μΑ |
| I _{EBO} | emitter-base cut-off current | V _{EB} = 5 V; I _C = 0 A; T _{amb} = 25 °C | | - | - | 100 | nA |
| h _{FE} | DC current gain | V _{CE} = 5 V; I _C = 2 mA; T _{amb} = 25 °C | | 63 | - | - | |
| | | V _{CE} = 2 V; I _C = 150 mA; T _{amb} = 25 °C | [1] | 63 | - | 250 | |
| | | V_{CE} = 2 V; I_{C} = 500 mA; T_{amb} = 25 °C | [1] | 40 | - | - | |
| V_{CEsat} | collector-emitter saturation voltage | I_{C} = 500 mA; I_{B} = 50 mA; T_{amb} = 25 °C | [1] | - | - | 500 | mV |
| V_{BE} | base-emitter voltage | V_{CE} = 2 V; I_{C} = 500 mA; T_{amb} = 25 °C | [1] | - | - | 1 | V |
| C _c | collector capacitance | V_{CB} = 10 V; I_{E} = 0 A; i_{e} = 0 A; f = 1 MHz; T_{amb} = 25 °C | | - | 4.5 | - | pF |
| f _T | transition frequency | $V_{CE} = 5 \text{ V}; I_{C} = 50 \text{ mA}; f = 100 \text{ MHz}; $ $T_{amb} = 25 ^{\circ}\text{C}$ | | 100 | 155 | - | MHz |
| Per device | | | | | | | |
| h _{FE1} /h _{FE2} | DC current gain matching | $V_{CE} = 5 \text{ V}; I_{C} = 2 \text{ mA}; T_{amb} = 25 \text{ °C}$ | | 0.95 | 1 | 1.05 | |
| V _{BE1} -V _{BE2} | base-emitter voltage matching | | [2] | - | - | 2 | mV |

Pulse test: $t_p \le 300~\mu s;~\delta \le 0.02$ The smaller of the two values is subtracted from the larger value.

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DC current gain as a function of collector Fig. 4. current; typical values

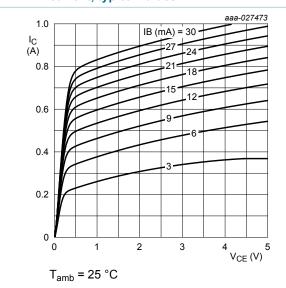
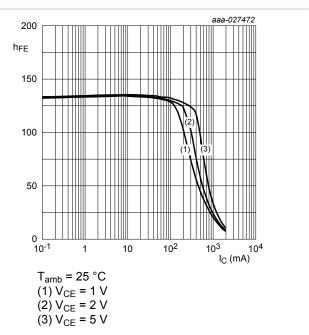
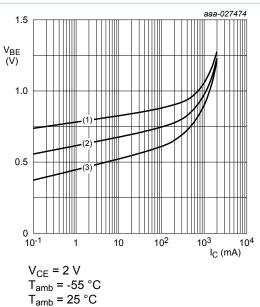


Fig. 6. Collector current as a function of collectoremitter voltage; typical values



DC current gain as a function of collector Fig. 5. current; typical values

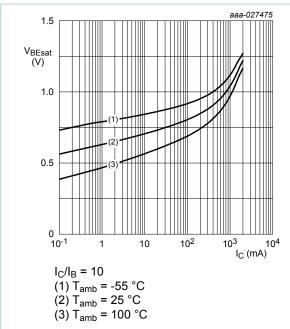


T_{amb} = 25 °C T_{amb} = 100 °C

Fig. 7. Base-emitter voltage as a function of collector current; typical values

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Base-emitter saturation voltage as a function of Fig. 9. Fig. 8. collector current; typical values

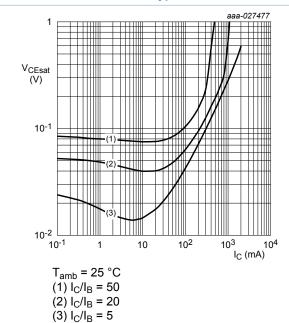
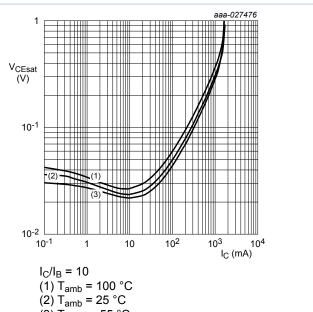


Fig. 10. Collector-emitter saturation voltage as a function of collector current; typical values



(3) $T_{amb} = -55 \, ^{\circ}C$

Collector-emitter saturation voltage as a function of collector current; typical values

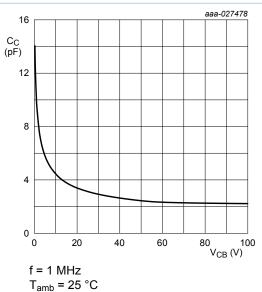


Fig. 11. Collector capacitance as a function of collector-base voltage; typical values

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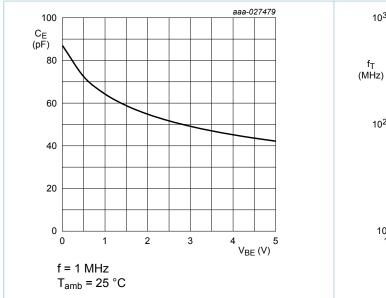


Fig. 12. Emitter capacitance as a function of emitterbase voltage; typical values

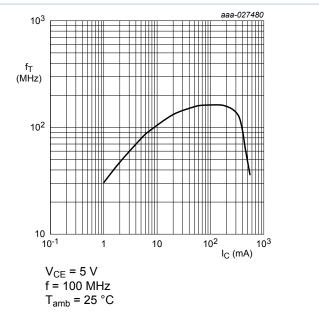


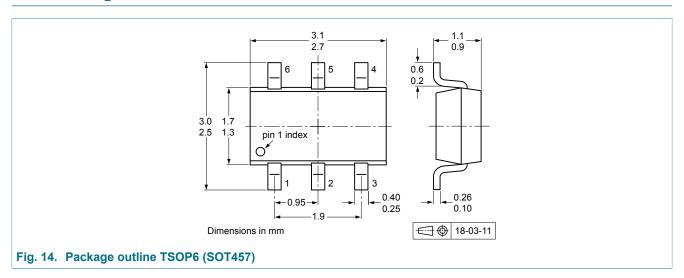
Fig. 13. Transition frequency as a function of collector current; typical values

11. Test information

Quality information

This product has been qualified in accordance with the Automotive Electronics Council (AEC) standard Q101 - *Stress test qualification for discrete semiconductors*, and is suitable for use in automotive applications.

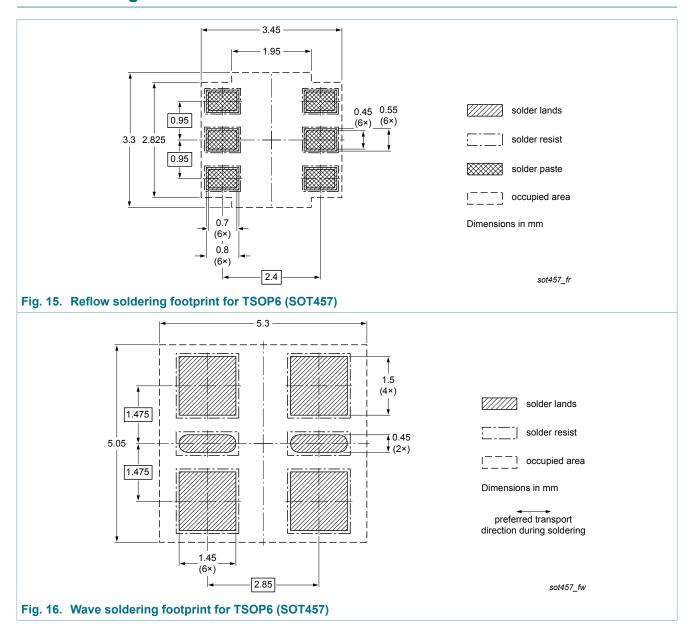
12. Package outline



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13. Soldering



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14. Revision history

Table 8. Revision history

| Data sheet ID | Release date | Data sheet status | Change notice | Supersedes |
|---------------|--------------|--------------------|---------------|------------|
| BCM56DS v.1 | 20180410 | Product data sheet | - | - |

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15. Legal information

Data sheet status

| Document status [1][2] | Product status [3] | Definition |
|--------------------------------------|--------------------|---|
| Objective [short] data sheet | Development | This document contains data from the objective specification for product development. |
| Preliminary [short] data sheet | Qualification | This document contains data from the preliminary specification. |
| Product [short] data sheet | Production | This document contains the product specification. |

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